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The fourteenth International Conference on Narrow Gap Semiconductors and Systems (NGS2-14) was held in Sendai, Japan, on July 13-17, 2009. We brought together 101 researchers from 15 countries to discuss recent advances and discoveries in the science and technology of narrow gap semiconductors (NGS). The previous thirteen conferences in this series were held in Dallas, U.S.A. (1970), Nice, France (1973), Warsaw, Poland (1977), Linz, Austria (1981), Gaithersburg, U.S.A. (1989), Southampton, U.K. (1992), Santa Fe, U.S.A. (1995), Shanghai, China (1997), Berlin, Germany (1999), Kanazawa, Japan (2001), Buffalo, U.S.A. (2003), Toulouse, France (2005), and Guildford, U.K. (2007). The research areas of the NGS2-14 were expanded from traditional NGS physics into device applications, including physics and novel effects in NGS, growth and characterization in NGS, devices consisting of NGS, novel systems and spins, THz radiation and detection, cascade laser, and low dimensional carbon systems. This time, the title of the conference was modified to be International Conference on Narrow Gap Semiconductors and Systems (NGS2). We decided to publish the proceedings in the newly launched online Elsevier journal "Physics Procedia". This has the advantage that all the published papers are freely available online.

It would not have been possible to hold the NGSS-14 Conference without the help of the international advisory committee, program committee, and secretary listed on the following page, to whom we are extremely grateful.

Junsaku Nitta
Chair

Hiro Munekata
Co-Chair